# RENESAS

# HD74HC386

Quad. 2-input Exclusive-OR Gates

REJ03D0623-0200 (Previous ADE-205-502) Rev.2.00 Mar 30, 2006

### Features

- High Speed Operation:  $t_{pd} = 11.5$  ns typ ( $C_L = 50$  pF)
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage:  $V_{CC} = 2 \text{ to } 6 \text{ V}$
- Low Input Current: 1 µA max
- Low Quiescent Supply Current:  $I_{CC}$  (static) = 1  $\mu$ A max (Ta = 25°C)
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC386P	DILP-14 pin	PRDP0014AB-B (DP-14AV)	Ρ	—
HD74HC386FPEL	SOP-14 pin (JEITA)	PRSP0014DF-B (FP-14DAV)	FP	EL (2,000 pcs/reel)
HD74HC386RPEL	SOP-14 pin (JEDEC)	PRSP0014DE-A (FP-14DNV)	RP	EL (2,500 pcs/reel)

Note: Please consult the sales office for the above package availability.

### **Function Table**

Inp	Inputs					
A	В	Y				
L	L	L				
L	Н	Н				
Н	L	Н				
Н	Н	L				

H: High level

L: Low level



### **Pin Arrangement**



### **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
Input / Output voltage	V <sub>IN</sub> , V <sub>OUT</sub>	–0.5 to V <sub>CC</sub> +0.5	V
Input / Output diode current	I <sub>IK</sub> , I <sub>OK</sub>	±20	mA
Output current	lo	±25	mA
V <sub>CC</sub> , GND current	I <sub>CC</sub> or I <sub>GND</sub>	±50	mA
Power dissipation	PT	500	mW
Storage temperature	Tstg	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

### **Recommended Operating Conditions**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V <sub>cc</sub>	V <sub>CC</sub> 2 to 6		
Input / Output voltage	V <sub>IN</sub> , V <sub>OUT</sub>	0 to V <sub>CC</sub>	V	
Operating temperature	Та	-40 to 85	°C	
		0 to 1000		V <sub>CC</sub> = 2.0 V
Input rise / fall time <sup>*1</sup>	t <sub>r</sub> , t <sub>f</sub>	0 to 500	ns	$V_{CC} = 4.5 V$
		0 to 400		$V_{CC} = 6.0 V$

Note: 1. This item guarantees maximum limit when one input switches. Waveform: Refer to test circuit of switching characteristics.



			Т	a = 25°	С	Ta = -40 to+85°C				
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Мах	Unit	Test Cor	nditions
Input voltage	VIH	2.0	1.5	_		1.5		V		
		4.5	3.15	—		3.15				
		6.0	4.2	—		4.2				
	VIL	2.0	_	—	0.5		0.5	V		
		4.5	_	—	1.35		1.35			
		6.0	_	—	1.8		1.8			
Output voltage	V <sub>OH</sub>	2.0	1.9	2.0		1.9		V	$Vin = V_{IH} \text{ or } V_{IL}$	I <sub>OH</sub> = -20 μA
		4.5	4.4	4.5		4.4				
		6.0	5.9	6.0		5.9				
		4.5	4.18	—		4.13				$I_{OH} = -4 \text{ mA}$
		6.0	5.68	—		5.63				$I_{OH} = -5.2 \text{ mA}$
	V <sub>OL</sub>	2.0	_	0.0	0.1		0.1	V	$Vin = V_{IH} \text{ or } V_{IL}$	I <sub>OL</sub> = 20 μA
		4.5	_	0.0	0.1		0.1			
		6.0	_	0.0	0.1	_	0.1			
		4.5	_	—	0.26		0.33			$I_{OL} = 4 \text{ mA}$
		6.0	_		0.26	_	0.33			I <sub>OL</sub> = 5.2 mA
Input current	lin	6.0	_		±0.1		±1.0	μΑ	$Vin = V_{CC} \text{ or } GN$	ID
Quiescent supply current	Icc	6.0		_	1.0	—	10	μA	$Vin = V_{CC} \text{ or } GN$	ID, Iout = 0 μA

## **Electrical Characteristics**

# Switching Characteristics ( $C_L = 50 \text{ pF}$ , Input $t_r = t_f = 6 \text{ ns}$ )

			Ta = 25°C		Ta = -40 to +85°C				
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Propagation delay	t <sub>PLH</sub>	2.0	_	-	120	—	150	ns	
time		4.5	_	12	24	—	30		
		6.0		—	20	—	26		
	t <sub>PHL</sub>	2.0	_	—	120	_	150	ns	
		4.5		12	24	—	30		
		6.0			20	_	26		
Output rise time	t <sub>TLH</sub>	2.0		—	75	—	95	ns	
		4.5		7	15	_	19		
		6.0	_	-	13	—	16		
Output fall time	t <sub>THL</sub>	2.0	_	—	75	—	95	ns	
		4.5	_	7	15	—	19		
		6.0	_	—	13	—	16		
Input capacitance	Cin	—	_	5	10	—	10	pF	

### **Test Circuit**





### Waveforms



### **Package Dimensions**







### HD74HC386

JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]			
P-SOP14-3.95x8.65-1.27	PRSP0014DE-A	FP-14DNV	0.13g	1		
	Index mark		H W	F		NOTE) 1. DIMENSIONS**1 (Nom)"AND**2" DO NOT INCLUDE MOLD FLASH. 2. DIMENSION**3"DOES NOT INCLUDE TRIM OFFSET.
					Terminal cross section ( Ni/Pd/Au plating )	Bimension in Millimeter:           Symbol         Min         Nom         Max           D          8.65         9.05           E          3.95            A2              A1         0.10         0.14         0.25
			<pre> </pre>			$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$
					Detail F	E          1.27           X          0.24           y          0.12           Z          0.63           L         0.40         0.60         1.27           L1          1.08



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